

TMC-1C42

1 GHz InGaAs PIN plus Pre-amplifier

FEATURES:

- Industry standard TO-46 package with cap lens.
- Optimized for fiber optic application.
- Suitable for long wavelength 1.25 Gbps applications.



ELECTRO-OPTICAL CHARACTERISTICS:

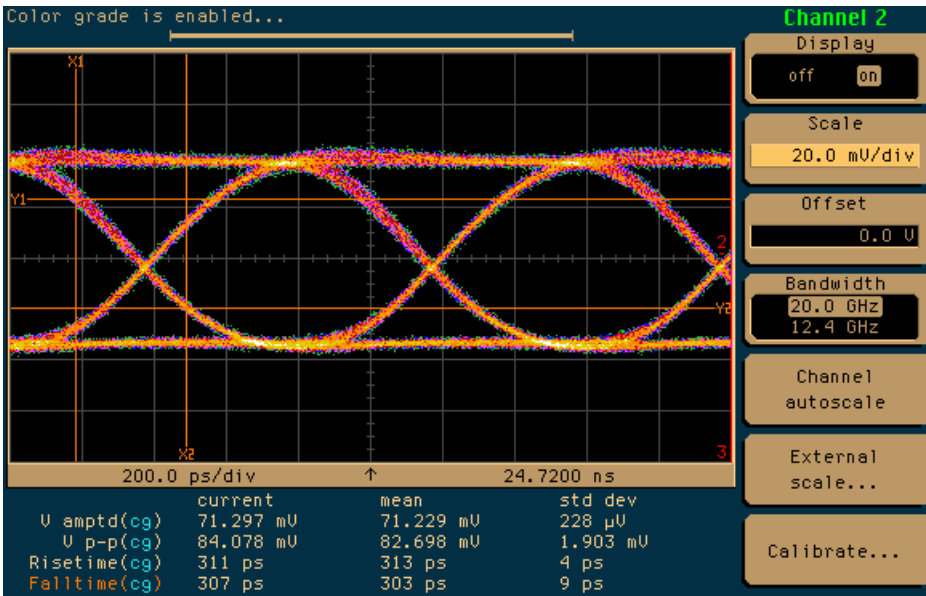
PARAMETERS	SYMBOL	MIN	TYP	MAX	UNIT	TEST CONDITIONS
Power Supply	V_{CC}	3.0		5.5	V	
Supply Current	I_{CC}		26	50	mA	no loads
Differential Responsivity	R_d	1.9	2.5	3.0	mV/ μ W	$R_{load} = 100 \text{ ohm}$, $P = -15 \text{ dBm @ } 50 \text{ MHz}$, 1310nm
Single Ended Responsivity	R_s	0.9	1.2	1.5	mV/ μ W	$R_{load} = 50 \text{ ohm}$, $P = -15 \text{ dBm @ } 50 \text{ MHz}$, 1310nm
Small-Signal Bandwidth	BW	750	920	1100	MHz	
Low-Frequency Cut off	LF		44		kHz	
Rise Time/Fall Time	t_r/t_f		300	400	ps	20 % ~ 80 %, $P = P = -15 \text{ dBm}$, 1310nm
Single Ended Output Impedance	R_O	48	50	52	ohm	
RMS Input Referred Noise			220	290	nW	
Maximum Differential Output Voltage		185	250	415	mV p-p	$P = 0 \text{ dBm}$, 1310nm
RMS Output Referred Noise	V_n			1.6	mV	$P = 0 \text{ dBm}$, 1310nm
Power Supply Rejection Ratio	PSRR		50		dB	
Wavelength	λ	1270		1380	nm	

ABSOLUTE MAXIMUM RATINGS:

PARAMETERS	MIN	MAX	UNIT	CONDITIONS
Storage Temperature	-40	100	°C	
Operating Temperature	-20	85	°C	
Lead Solder Temperature		260	°C	10 seconds

Eye Diagram:

$R_{load} = 50\text{ ohm}$, $P = -15\text{ dBm @ }1250\text{ Mbps}$, 1310nm , $\text{PRBS} = 2^7-1$,



$t_r = 311\text{ps}$, $t_f = 307\text{ps}$

OUTLINE DIMENSIONS:

